

Francois Sfigakis

List of Publications by Year in descending order

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17

papers

652

citations

1040056

9

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940533

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all docs

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docs citations

17

times ranked

1240

citing authors

#	ARTICLE	IF	CITATIONS
1	One Million Percent Tunnel Magnetoresistance in a Magnetic van der Waals Heterostructure. <i>Nano Letters</i> , 2018, 18, 4885-4890.	9.1	230
2	Evolution of interlayer and intralayer magnetism in three atomically thin chromium trihalides. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2019, 116, 11131-11136.	7.1	223
3	Zero-bias anomaly in quantum wires. <i>Physical Review B</i> , 2009, 79, .	3.2	42
4	Fabrication and characterization of ambipolar devices on an undoped AlGaAs/GaAs heterostructure. <i>Applied Physics Letters</i> , 2012, 100, .	3.3	37
5	Distinguishing impurity concentrations in GaAs and AlGaAs using very shallow undoped heterostructures. <i>Applied Physics Letters</i> , 2010, 97, .	3.3	23
6	Statistical study of conductance properties in one-dimensional quantum wires focusing on the 0.7 anomaly. <i>Physical Review B</i> , 2014, 90, .	3.2	21
7	Ultra-shallow quantum dots in an undoped GaAs/AlGaAs two-dimensional electron gas. <i>Applied Physics Letters</i> , 2013, 102, 103507.	3.3	17
8	Demonstration and characterization of an ambipolar high mobility transistor in an undoped GaAs/AlGaAs quantum well. <i>Applied Physics Letters</i> , 2013, 102, .	3.3	16
9	Dependence of the 0.7 anomaly on the curvature of the potential barrier in quantum wires. <i>Physical Review B</i> , 2015, 91, .	3.2	10
10	Benefits of using undoped GaAs/AlGaAs heterostructures: A case study of the zero-bias bias anomaly in quantum wires. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2010, 42, 1200-1204.	2.7	8
11	Effect of Split Gate Size on the Electrostatic Potential and 0.7 Anomaly within Quantum Wires on a Modulation-Doped<math display="block">\text{Effect of Split Gate Size on the Electrostatic Potential and 0.7 Anomaly within Quantum Wires on a Modulation-Doped } \text{Effect of Split Gate Size on the Electrostatic Potential and 0.7 Anomaly within Quantum Wires on a Modulation-Doped } \text{Effect of Split Gate Size on the Electrostatic Potential and 0.7 Anomaly within Quantum Wires on a Modulation-Doped } \text{Effect of Split Gate Size on the Electrostatic Potential and 0.7 Anomaly within Quantum Wires on a Modulation-Doped } <td>3.8</td> <td>8</td>	3.8	8
12	Single-particle probing of edge-state formation in a graphene nanoribbon. <i>Physical Review B</i> , 2012, 85, .	3.2	5
13	Non-adiabatic single-electron pumps in a dopant-free GaAs/AlGaAs 2DEG. <i>Applied Physics Letters</i> , 2021, 119, .	3.3	5
14	Orientation of hole quantum Hall nematic phases in an out-of-plane electric field. <i>Physical Review B</i> , 2019, 99, .	3.2	3
15	Vortex detection and quantum transport in mesoscopic graphene Josephson-junction arrays. <i>Physical Review B</i> , 2015, 91, .	3.2	2
16	Effects of biased and unbiased illuminations on two-dimensional electron gases in dopant-free GaAs/AlGaAs. <i>Physical Review B</i> , 2022, 105, .	3.2	2
17	Beyond modulation doping: Engineering a semiconductor to be ambipolar, or making an ON-OFF-ON transistor., 2014, ,.	0	0